## NSN 5961-01-102-8557

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View Online at https://aerobasegroup.com/nsn/5961-01-102-8557 **Inclosure Material:** Metal **Overall Length:** 0.730 inches **Overall Diameter:** 0.800 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 0.25 amperes source cutoff current **Power Rating Per Characteristic:** 1.25 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 4 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: